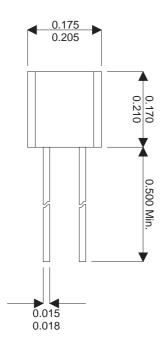
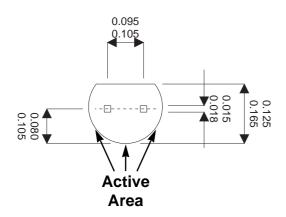


## **SMP550G-X2**

#### **MECHANICAL DATA**

Dimensions in inches.





TO-92 Package

### P.I.N. PHOTODIODE



#### **FEATURES**

- WATER CLEAR PLASTIC
- WIDE SPECTRAL RESPONSE
- 0.1" (2.54mm) LEAD SPACING
- LOW DARK CURRENT
- SUITABLE FOR REMOTE CONTROL
- HIGH SENSITIVITY

#### DESCRIPTION

The SMP550G-X2 is a silicon PIN photodiode which is incorporated in a colourless plastic package. The terminals are solder tabs with 0.1" (2.54mm) spacing. Due to its design the diode can be assembled vertically on PC board.

Arrays can be realised by multiple arrangements. This versatile photo detector can be used as a diode as well as a voltage cell.

The PIN photodiode is outstanding for low junction capacitance, high cut off frequency and short switching time. It is particularly suitable for IR sound transmission and remote control.

## ABSOLUTE MAXIMUM RATINGS (T<sub>case</sub> = 25°C unless otherwise stated)

Operating temperature range	-40°C to +70°C
Storage temperature range	-45°C to +80°C
Temperature coefficient of responsively	0.35% per °C
Temperature coefficient of dark current	x2 per 8°C rise
Reverse Breakdown Voltage	60V



# **SMP550G-X2**

## **CHARACTERISTICS** (T<sub>amb</sub>=25°C unless otherwise stated)

Characteristic	Test Conditions.		Min.	Тур.	Max.	Units
Responsively	λ at 900nm		0.45	0.55		A/W
Active Area				5.19		mm²
Dark Current	E = 0 Dark	1V Reverse		0.25	2	nA
	E = 0 Dark	10V Reverse		1	5	
Breakdown Voltage	E = 0 Dark	10µA Reverse	60	80		V
Capacitance	E = 0 Dark	0V Reverse		30	55	pF
	E = 0 Dark	20V Reverse		5	10	
Rise Time	30V Reverse		8			ns
	50Ω			O		
NEP	900nm			9.8		W/√Hz

